

# 7MBP200RA060

## IGBT-IPM R series

600V / 200A 7 in one-package

### Features

- Temperature protection provided by directly detecting the junction temperature of the IGBTs
- Low power loss and soft switching
- High performance and high reliability IGBT with overheating protection
- Higher reliability because of a big decrease in number of parts in built-in control circuit



### Maximum ratings and characteristics

- Absolute maximum ratings(at  $T_c=25^\circ\text{C}$  unless otherwise specified)

Item	Symbol	Rating		Unit		
		Min.	Max.			
DC bus voltage	$V_{DC}$	0	450	V		
DC bus voltage (surge)	$V_{DC(surge)}$	0	500	V		
DC bus voltage (short operating)	$V_{SC}$	200	400	V		
Collector-Emitter voltage	$V_{CES}$	0	600	V		
DB Reverse voltage	$V_R$	-	600	V		
INV	Collector current	DC	$I_C$	-	200	A
		1ms	$I_{CP}$	-	400	A
		Duty=57.8%	$-I_C$	-	200	A
	Collector power dissipation	One transistor	$P_C$	-	735	W
DB	Collector current	DC	$I_C$	-	75	A
		1ms	$I_{CP}$	-	150	A
	Forward current of Diode		$I_F$	-	75	A
	Collector power dissipation	One transistor	$P_C$	-	320	W
Junction temperature		$T_j$	-	150	$^\circ\text{C}$	
Input voltage of power supply for Pre-Driver		$V_{CC*1}$	0	20	V	
Input signal voltage		$V_{in} *2$	0	$V_Z$	V	
Input signal current		$I_{in}$	-	1	mA	
Alarm signal voltage		$V_{ALM*3}$	0	$V_{CC}$	V	
Alarm signal current		$I_{ALM} *4$	-	15	mA	
Storage temperature		$T_{stg}$	-40	125	$^\circ\text{C}$	
Operating case temperature		$T_{op}$	-20	100	$^\circ\text{C}$	
Isolating voltage (Case-Terminal)		$V_{iso} *5$	-	AC2.5	kV	
Screw torque	Mounting (M5)	-	3.5 *6	N·m		
	Terminal (M5)	-	3.5 *6	N·m		

\*1 Apply  $V_{CC}$  between terminal No. 3 and 1, 6 and 4, 9 and 7, 11 and 10.

\*2 Apply  $V_{in}$  between terminal No. 2 and 1, 5 and 4, 8 and 7, 12,13,14,15 and 10.

\*3 Apply  $V_{ALM}$  between terminal No. 16 and 10.

\*4 Apply  $I_{ALM}$  to terminal No. 16.

\*5 50Hz/60Hz sine wave 1 minute.

\*6 Recommendable Value : 2.5 to 3.0 N·m

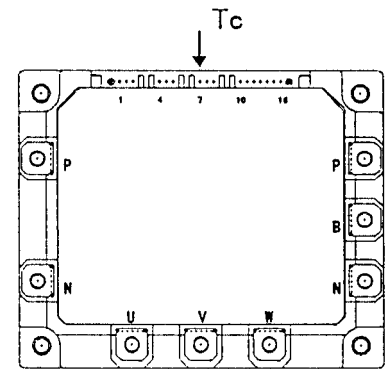


Fig.1 Measurement of case temperature

- Electrical characteristics of power circuit (at  $T_c=T_j=25^\circ\text{C}$ ,  $V_{CC}=15\text{V}$ )

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
INV	Collector current at off signal input	$I_{CES}$	$V_{CE}=600\text{V}$ input terminal open	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=200\text{A}$	-	-	2.8	V
	Forward voltage of FWD	$V_F$	$-I_C=200\text{A}$	-	-	3.0	V
DB	Collector current at off signal input	$I_{CES}$	$V_{CE}=600\text{V}$ input terminal open	-	-	1.0	mA
	Collector-Emitter saturation voltage	$V_{CE(sat)}$	$I_C=75\text{A}$	-	-	2.8	V
	Forward voltage of Diode	$V_F$	$-I_C=75\text{A}$	-	-	3.3	V

● Electrical characteristics of control circuit(at Tc=Tj=25°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit	
Power supply current of P-line side Pre-driver(one unit)	I <sub>ccp</sub>	fsw=0 to 15kHz Tc=-20 to 100°C *7	6	-	32	mA	
Power supply current of N-line side three Pre-driver	I <sub>ccn</sub>	fsw=0 to 15kHz Tc=-20 to 100°C *7	24	-	114	mA	
Input signal threshold voltage (on/off)	V <sub>in(th)</sub>	ON	1.00	1.35	1.70	V	
		OFF	1.70	2.05	2.40	V	
Input zener voltage	V <sub>z</sub>	R <sub>in</sub> =20k ohm	-	8.0	-	V	
Over heating protection temperature level	T <sub>COH</sub>	VDC=0V, I <sub>c</sub> =0A, Case temperature, Fig.1	110	-	125	°C	
Hysteresis	T <sub>CH</sub>		-	20	-	°C	
IGBT chips over heating protection temperature level	T <sub>JOH</sub>	surface of IGBT chips	150	-	-	°C	
Hysteresis	T <sub>JH</sub>		-	20	-	°C	
Collector current protection level	INV	I <sub>oc</sub>	T <sub>j</sub> =125°C Collector current	300	-	-	A
	DB	I <sub>oc</sub>	T <sub>j</sub> =125°C Collector current	113	-	-	A
Over current protection delay time (Fig.2)	t <sub>DOC</sub>	T <sub>j</sub> =25°C Fig.2	-	10	-	μs	
Under voltage protection level	V <sub>UV</sub>		11.0	-	12.5	V	
Hysteresis	V <sub>H</sub>		0.2	-	-	V	
Alarm signal hold time	t <sub>ALM</sub>		1.5	2	-	ms	
SC protection delay time	t <sub>SC</sub>	T <sub>j</sub> =25°C Fig.3	-	-	12	μs	
Limiting resistor for alarm	R <sub>ALM</sub>		1425	1500	1575	ohm	

\*7 Switching frequency of IPM

● Dynamic characteristics(at Tc=Tj=125°C, Vcc=15V)

Item	Symbol	Condition	Min.	Typ.	Max.	Unit
Switching time (IGBT)	ton	I <sub>C</sub> =200A, VDC=300V	0.3	-	-	μs
	toff		-	-	3.6	μs
Switching time (FWD)	t <sub>tr</sub>	I <sub>F</sub> =200A, VDC=300V	-	-	0.4	μs

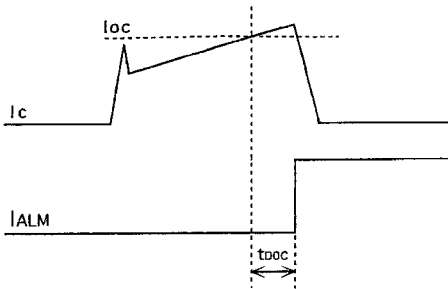


Fig.2 Definition of OC delay time

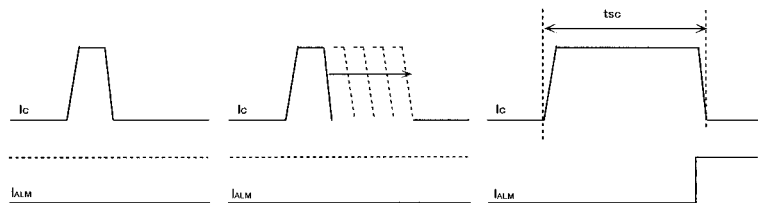


Fig.3 Definition of tsc

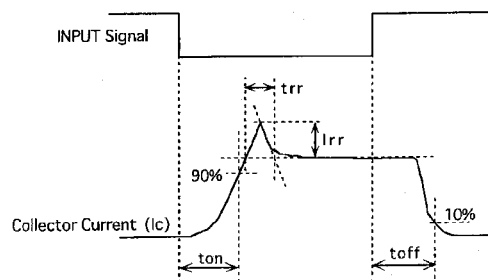


Fig.4 Definition of switching time

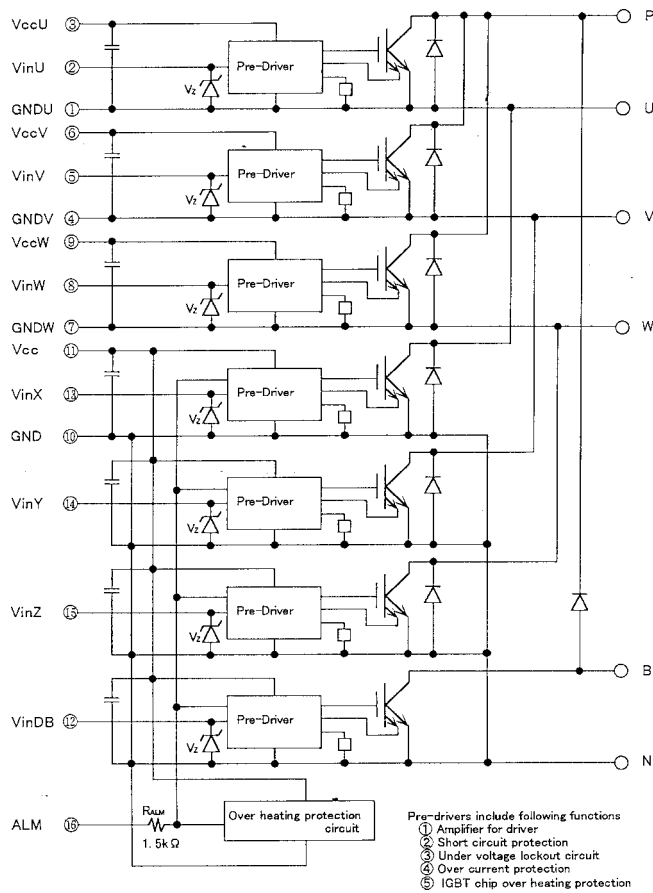
● Thermal characteristics(Tc=25°C)

Item	Symbol	Typ.	Max.	Unit	
Junction to Case thermal resistance	INV	IGBT	-	0.17	°C/W
		FWD	-	0.36	°C/W
	DB	IGBT	-	0.39	°C/W
Case to fin thermal resistance with compound	R <sub>th(c-f)</sub>	0.05	-	°C/W	

● Recommendable value

Item	Symbol	Min.	Typ.	Max.	Unit	
DC bus voltage	V <sub>DC</sub>	200	-	400	V	
Operating power supply voltage range of Pre-driver	V <sub>CC</sub>	13.5	15	16.5	V	
Switching frequency of IPM	fsw	1	-	20	kHz	
Screw torque	Mounting (M5)	-	2.5	-	3.0	N·m
	Terminal (M5)	-	2.5	-	3.0	N·m

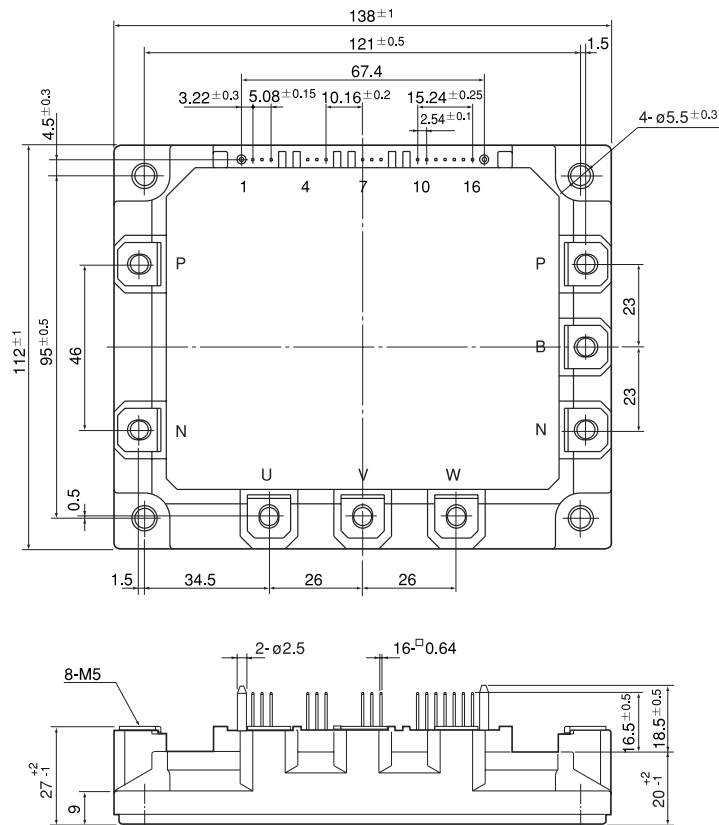
Block diagram



Pre-drivers include following functions  
 a) Amplifier for driver  
 b) Short circuit protection  
 c) Undervoltage lockout circuit  
 d) Over current protection  
 e) IGBT chip over heating protection

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 ① Amplifier for driver  
 ② Short circuit protection  
 ③ Under voltage lockout circuit  
 ④ Over current protection  
 ⑤ IGBT chip over heating protection

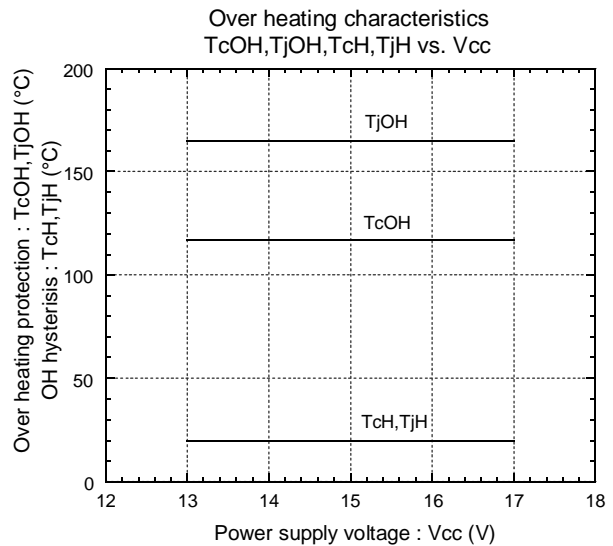
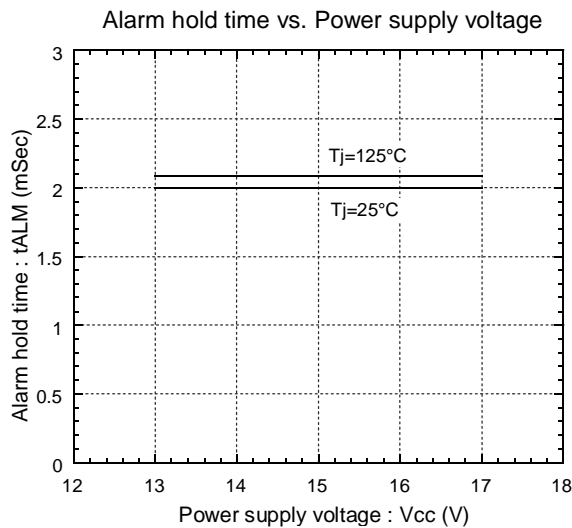
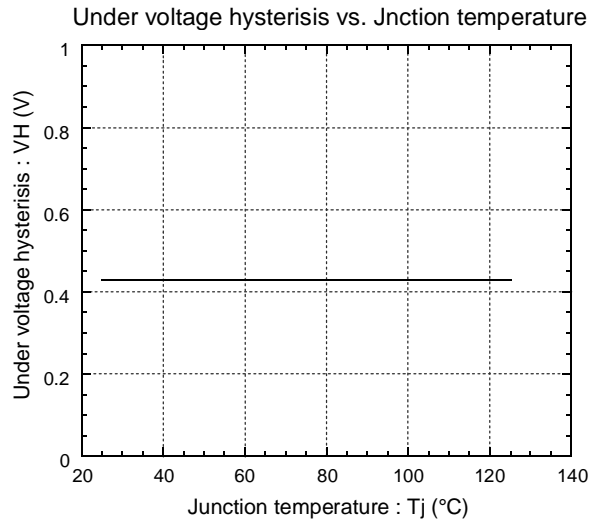
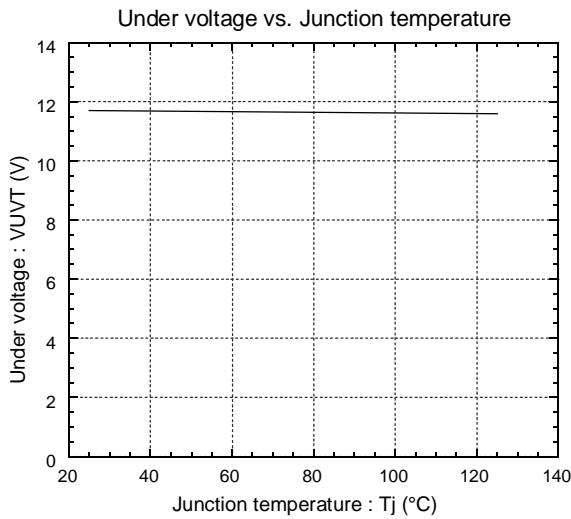
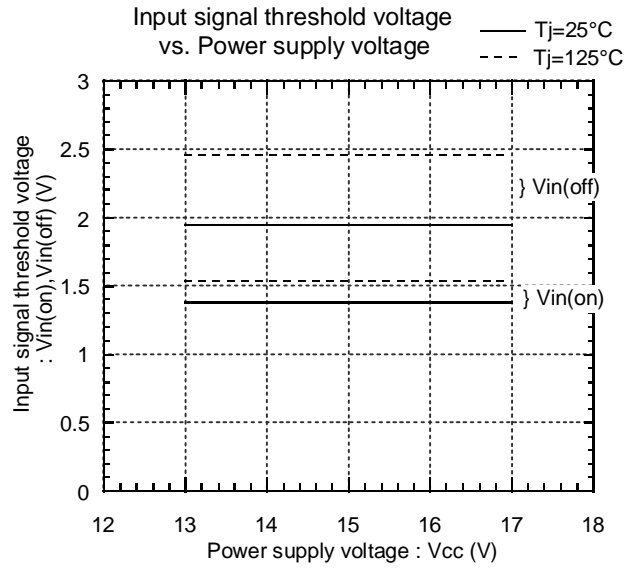
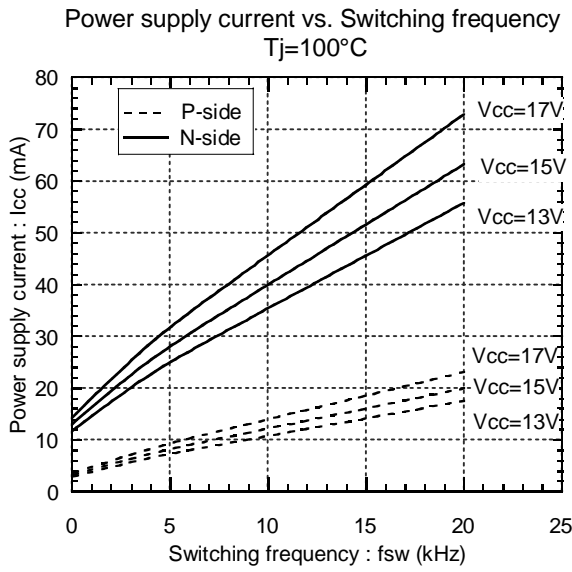
Outline drawings, mm



Mass : 920g

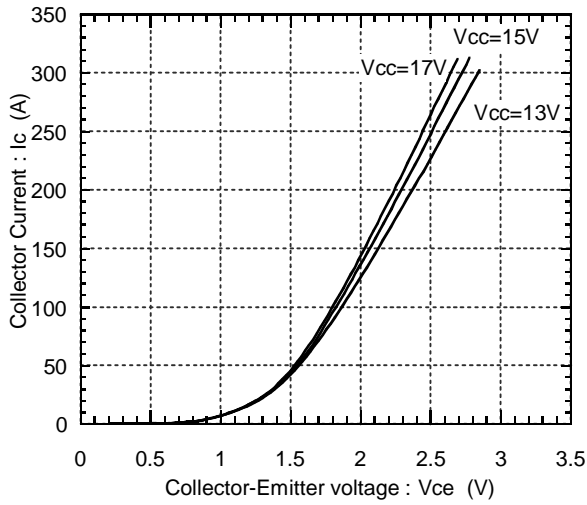
Characteristics (Representative)

Control circuit

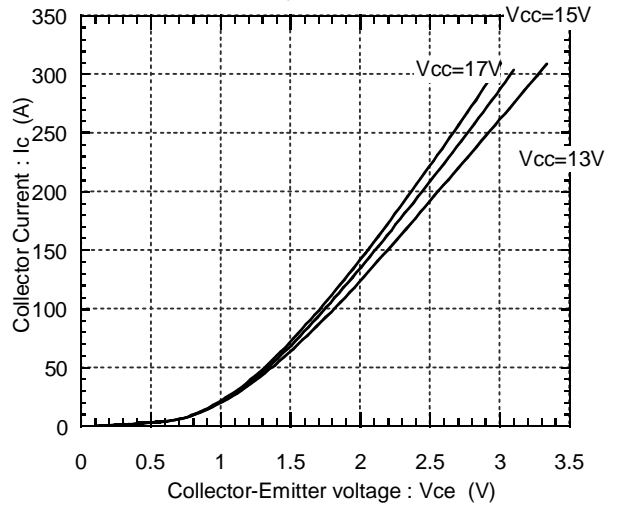


● Inverter

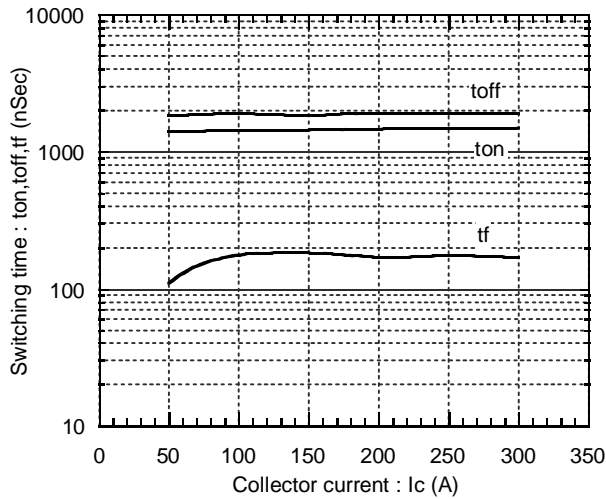
Collector current vs. Collector-Emittter voltage  
T<sub>j</sub>=25°C



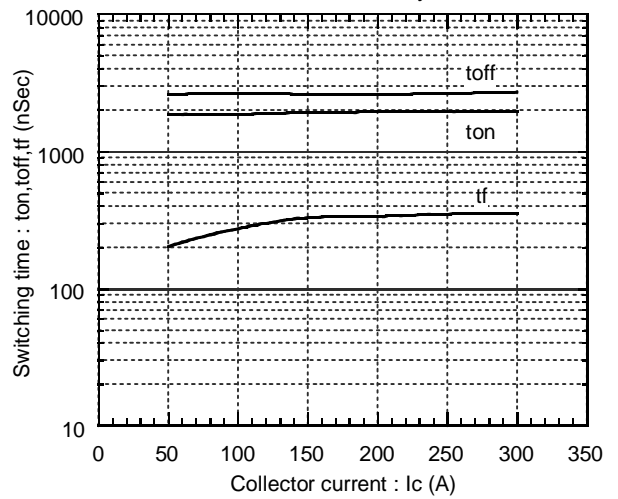
Collector current vs. Collector-Emittter voltage  
T<sub>j</sub>=125°C



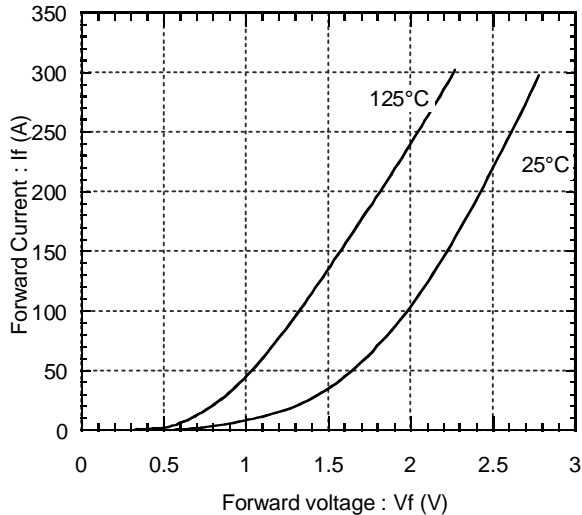
Switching time vs. Collector current  
E<sub>dc</sub>=300V, V<sub>cc</sub>=15V, T<sub>j</sub>=25°C



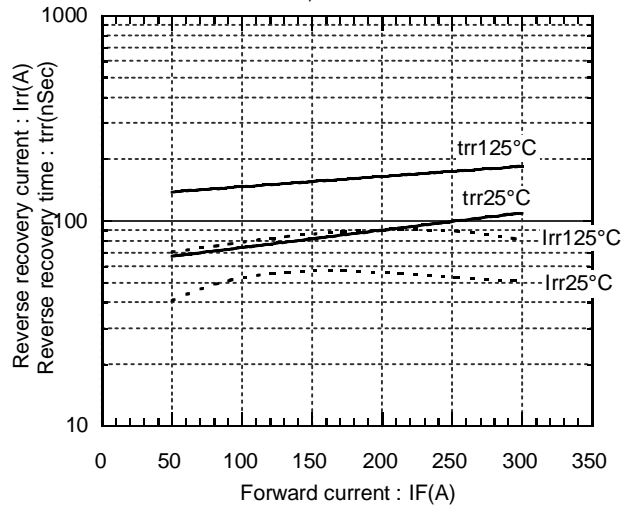
Switching time vs. Collector current  
E<sub>dc</sub>=300V, V<sub>cc</sub>=15V, T<sub>j</sub>=125°C

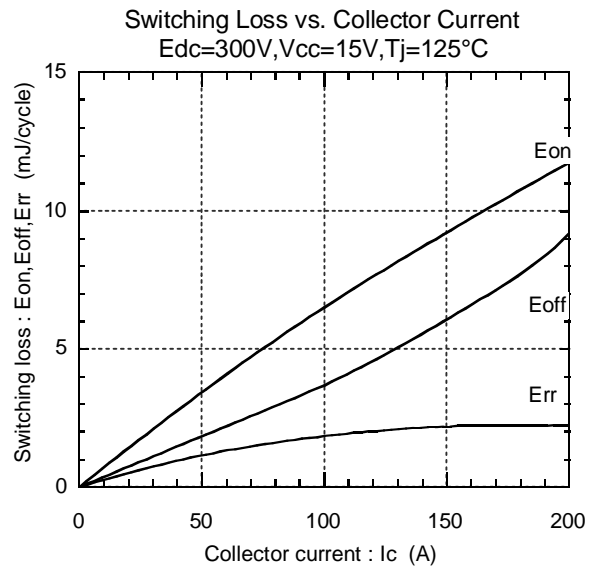
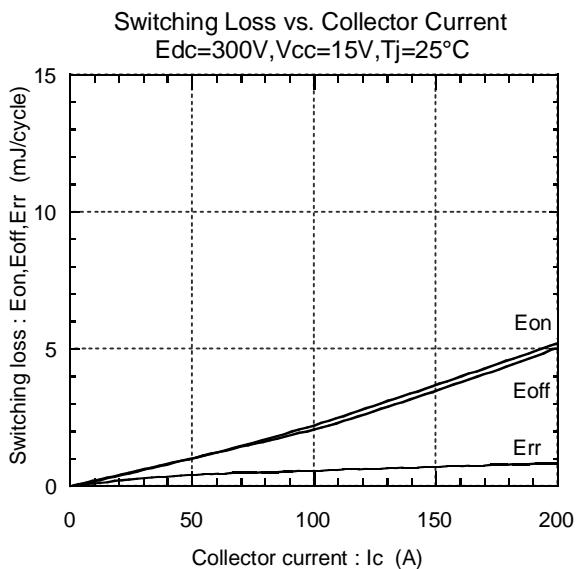
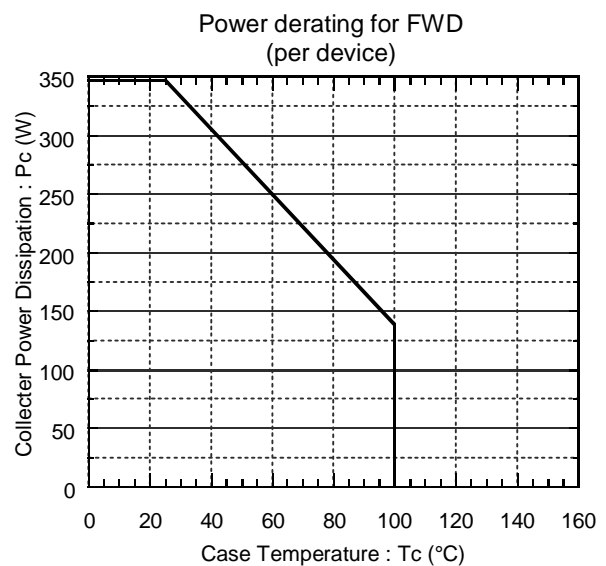
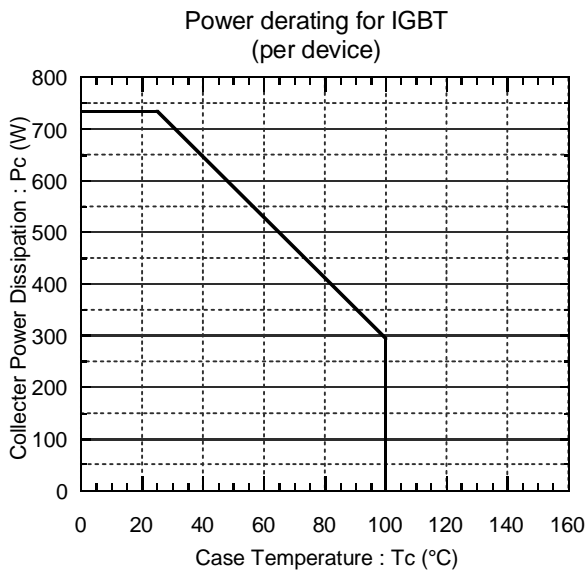
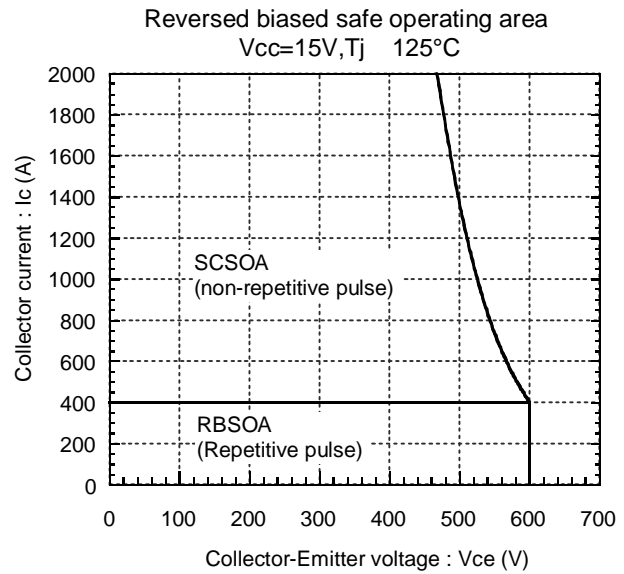
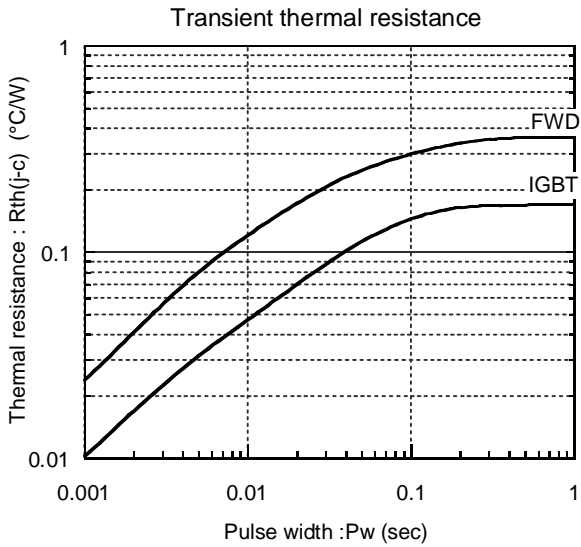


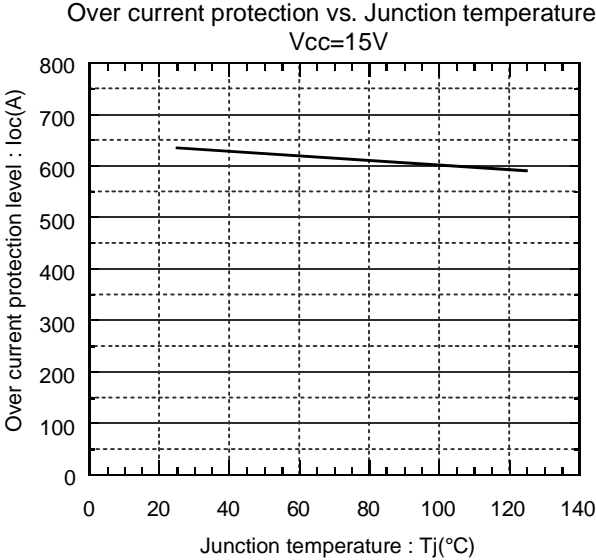
Forward current vs. Forward voltage



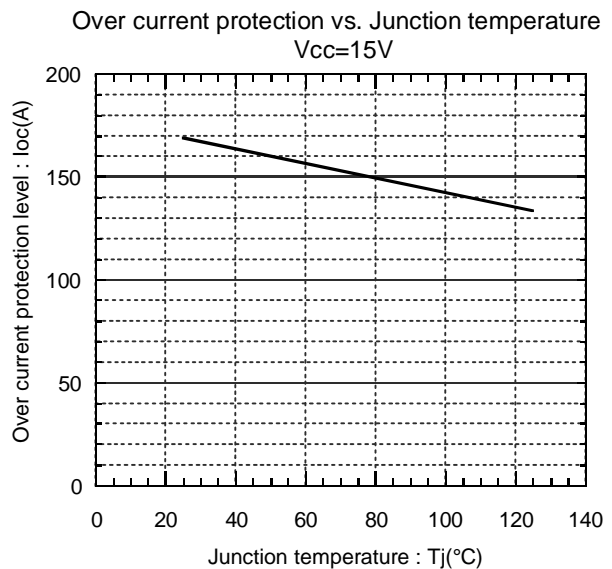
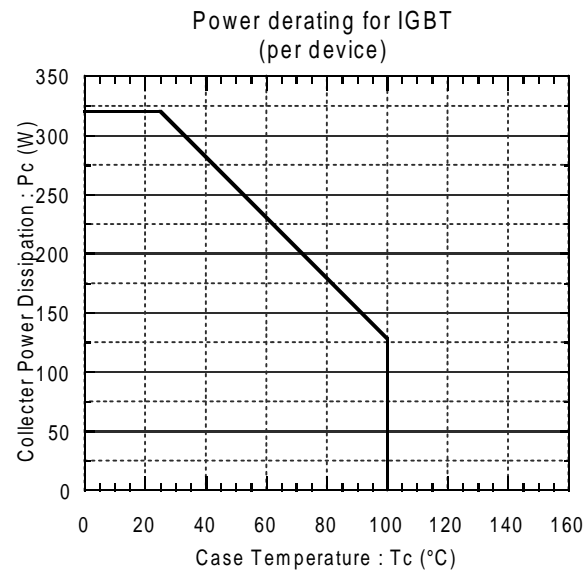
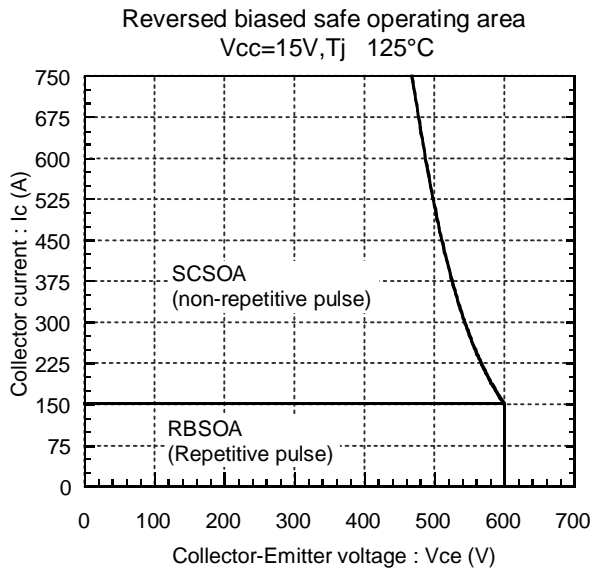
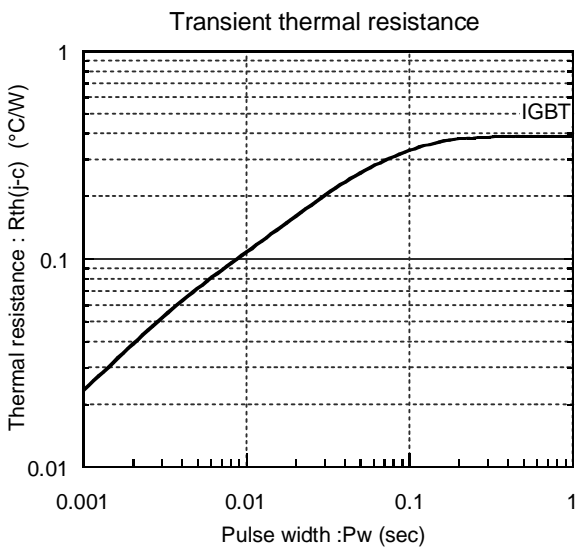
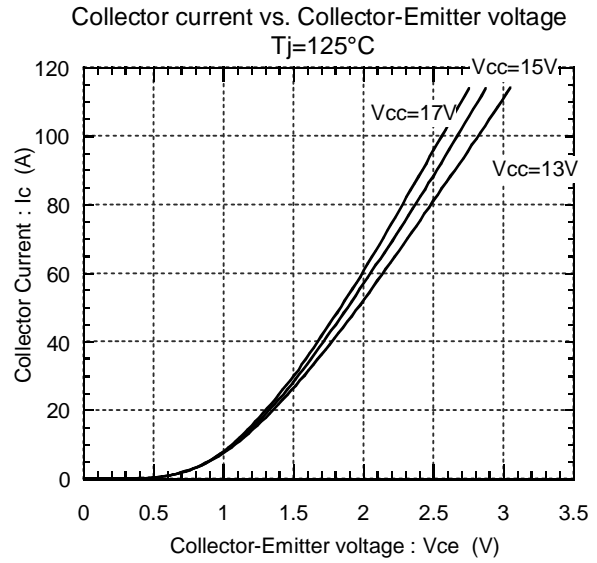
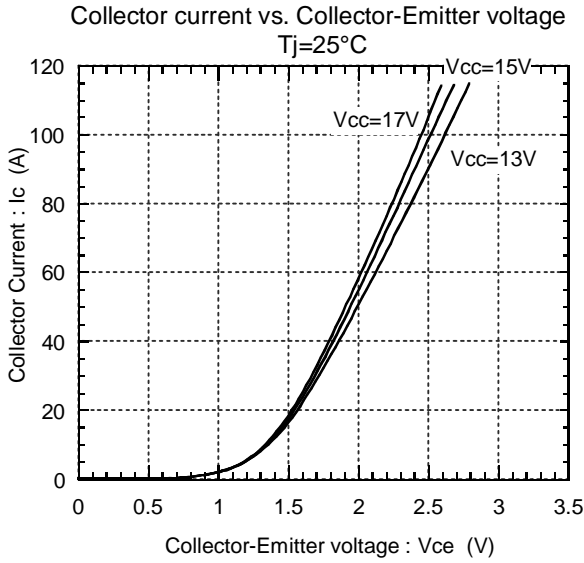
Reverse recovery characteristics  
trr, Irr vs. IF







● Brake





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